

GENERAL PURPOSE APPLICATION.
SWITCHING APPLICATION.

FEATURES

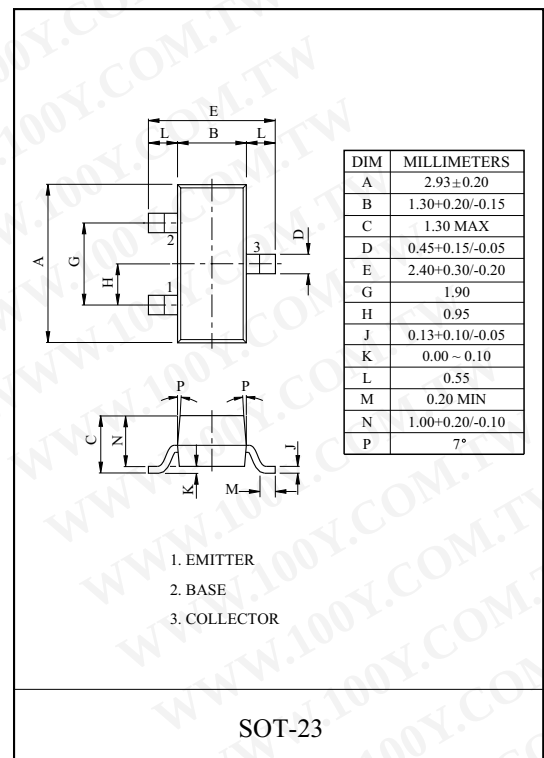
- Excellent h_{FE} Linearity
: $h_{FE}(I_C=0.1mA)/h_{FE}(I_C=2mA)=0.95(Typ.)$.
- Low Noise : $NF=1dB(Typ.)$ at $f=1kHz$.
- Complementary to KTC9015S.

MAXIMUM RATING ($T_a=25^\circ C$)

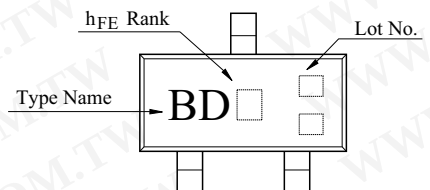
CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	60	V
Collector-Emitter Voltage	V_{CEO}	50	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I_C	150	mA
Emitter Current	I_E	-150	mA
Collector Power Dissipation	P_C^*	350	mW
Junction Temperature	T_j	150	$^\circ C$
Storage Temperature Range	T_{stg}	-55 ~ 150	$^\circ C$

* P_C : Package Mounted On 99.5% Alumina ($10 \times 8 \times 0.6mm$)

勝特力材料 886-3-5753170
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Marking

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ C$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB}=50V, I_E=0$	-	-	50	nA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=5V, I_C=0$	-	-	100	nA
DC Current Gain	h_{FE} (Note)	$V_{CE}=5V, I_C=1mA$	100	-	1000	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=100mA, I_B=10mA$	-	0.1	0.25	V
Transition Frequency	f_T	$V_{CE}=10V, I_C=1mA, f=100MHz$	60	-	-	MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=10V, I_E=0, f=1MHz$	-	2.0	3.5	pF
Noise Figure	NF	$V_{CE}=6V, I_C=0.1mA, R_g=10k\Omega, f=1kHz$	-	1.0	10	dB

Note : h_{FE} Classification B:100 ~ 300, C:200 ~ 600, D:400 ~ 1000